



# PDTA113EMB,315 Information



For Reference Only

Part Number PDTA113EMB,315 Manufacturer Nexperia USA Inc.

Category Discrete Semiconductor Products

Transistors - Bipolar (BJT) - Single, Pre-Biased

**Description** TRANS PREBIAS PNP 250MW 3DFN

Package 3-XFDFN

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

## **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









## PDTA113EMB,315 Specifications

	Report errors?
Supplier Device Package	3-DFN1006B (0.6x1)
Package / Case	3-XFDFN
Mounting Type	Surface Mount
Power - Max	250mW
Frequency - Transition	180MHz
Current - Collector Cutoff (Max)	100nA (ICBO)
Vce Saturation (Max) @ Ib, Ic	150mV @ 1.5mA, 30mA
DC Current Gain (hFE) (Min) @ Ic, Vce	30 @ 40mA, 5V
Resistor - Emitter Base (R2) (Ohms)	1k
Resistor - Base (R1) (Ohms)	1k
Voltage - Collector Emitter Breakdown (Max)	50V
Current - Collector (Ic) (Max)	100mA
Transistor Type	PNP - Pre-Biased
Series	-
Package	3-XFDFN
	Transistors - Bipolar (BJT) - Single, Pre-Biased
Category	Discrete Semiconductor Products
Manufacturer	Nexperia USA Inc.
Manufacturer Part Number	PDTA113EMB,315

## PDTA113EMB,315 Guarantees



### **Quality Guarantees**

We provide 90 days warranty. \*

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



#### **Service Guarantees**

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

### PDTA113EMB,315 Payment Methods





















### PDTA113EMB,315 Shipping Methods













If you have any question about PDTA113EMB,315, please do not hesitate to contact us!

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